

# KS250-Bidirectional thyristor

4000-4500 V<sub>DRM</sub>

## HIGH POWER BIDIRECTIONAL THYRISTOR

### Features

- . Amplifying Gate Configuration
- . Two thyristors integrated into one wafer
- . Blocking capability up to 4500 volts
- . High power capability
- . Full cold

**Gating**

Parameter	Symbol	Min.	Max.	Typ.	Units	Conditions
					Y	



